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[International Rectifier \(Infineon Technologies Americas Corp.\)
IRF3704](#)

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International IR Rectifier

SMPS MOSFET

PD - 93888B

IRF3704
IRF3704S
IRF3704L

HEXFET® Power MOSFET

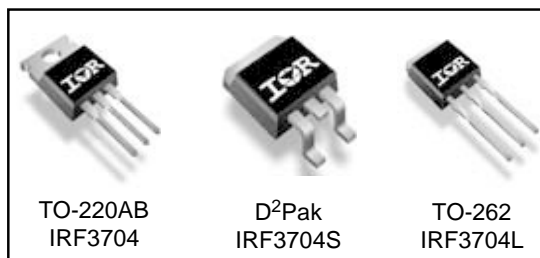
Applications

- High Frequency DC-DC Isolated Converters with Synchronous Rectification for Telecom and Industrial use
- High Frequency Buck Converters for Computer Processor Power

V_{DS}	R_{DS(on)} max	I_D
20V	9.0mΩ	77A^⑤

Benefits

- Ultra-Low Gate Impedance
- Very Low R_{DS(on)}
- Fully Characterized Avalanche Voltage and Current



Absolute Maximum Ratings

Symbol	Parameter	Max.	Units
V _{DS}	Drain-Source Voltage	20	V
V _{GS}	Gate-to-Source Voltage	± 20	V
I _D @ T _C = 25°C	Continuous Drain Current, V _{GS} @ 10V	77 ^⑤	A
I _D @ T _C = 70°C	Continuous Drain Current, V _{GS} @ 10V	64	
I _{DM}	Pulsed Drain Current ^①	308	
P _D @ T _C = 25°C	Maximum Power Dissipation ^③	87	W
P _D @ T _C = 70°C	Maximum Power Dissipation ^③	61	W
	Linear Derating Factor	0.59	mW/°C
T _J , T _{STG}	Junction and Storage Temperature Range	-55 to + 175	°C

Thermal Resistance

	Parameter	Typ.	Max.	Units
R _{θJC}	Junction-to-Case	—	1.73	°C/W
R _{θCS}	Case-to-Sink, Flat, Greased Surface ^④	0.50	—	
R _{θJA}	Junction-to-Ambient ^④	—	62	
R _{θJA}	Junction-to-Ambient (PCB mount)*	—	40	

* When mounted on 1" square PCB (FR-4 or G-10 Material) .
For recommended footprint and soldering techniques refer to application note #AN-994

Notes ① through ④ are on page 10

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Static @ T_J = 25°C (unless otherwise specified)

	Parameter	Min.	Typ.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source Breakdown Voltage	20	—	—	V	V _{GS} = 0V, I _D = 250μA
ΔV _{(BR)DSS/ΔT_J}	Breakdown Voltage Temp. Coefficient	—	0.021	—	V/°C	Reference to 25°C, I _D = 1mA
R _{DS(on)}	Static Drain-to-Source On-Resistance	—	6.3	9.0	mΩ	V _{GS} = 10V, I _D = 15A ③
		—	9.8	13.5		V _{GS} = 4.5V, I _D = 12A ③
V _{GS(th)}	Gate Threshold Voltage	1.0	—	3.0	V	V _{DS} = V _{GS} , I _D = 250μA
I _{DSS}	Drain-to-Source Leakage Current	—	—	20	μA	V _{DS} = 16V, V _{GS} = 0V
		—	—	100		V _{DS} = 16V, V _{GS} = 0V, T _J = 125°C
I _{GSS}	Gate-to-Source Forward Leakage	—	—	200	nA	V _{GS} = 16V
	Gate-to-Source Reverse Leakage	—	—	-200		V _{GS} = -16V

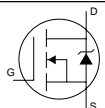
Dynamic @ T_J = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
g _{fs}	Forward Transconductance	42	—	—	S	V _{DS} = 10V, I _D = 57A
Q _g	Total Gate Charge	—	19	—	nC	I _D = 28.4A V _{DS} = 10V V _{GS} = 4.5V ③
Q _{gs}	Gate-to-Source Charge	—	8.1	—		
Q _{gd}	Gate-to-Drain ("Miller") Charge	—	6.4	—		
Q _{oss}	Output Gate Charge	—	16	24		
t _{d(on)}	Turn-On Delay Time	—	8.4	—	ns	V _{DD} = 10V I _D = 28.4A R _G = 1.8Ω V _{GS} = 4.5V ③
t _r	Rise Time	—	98	—		
t _{d(off)}	Turn-Off Delay Time	—	12	—		
t _f	Fall Time	—	5.0	—		
C _{iss}	Input Capacitance	—	1996	—	pF	V _{GS} = 0V V _{DS} = 10V f = 1.0MHz
C _{oss}	Output Capacitance	—	1085	—		
C _{rss}	Reverse Transfer Capacitance	—	155	—		

Avalanche Characteristics

Symbol	Parameter	Typ.	Max.	Units
E _{AS}	Single Pulse Avalanche Energy②	—	216	mJ
I _{AR}	Avalanche Current①	—	71	A

Diode Characteristics

Symbol	Parameter	Min.	Typ.	Max.	Units	Conditions
I _S	Continuous Source Current (Body Diode)	—	—	77⑤	A	MOSFET symbol showing the integral reverse p-n junction diode. 
I _{SM}	Pulsed Source Current (Body Diode) ①	—	—	308		
V _{SD}	Diode Forward Voltage	—	0.88	1.3	V	T _J = 25°C, I _S = 35.5A, V _{GS} = 0V ③
		—	0.82	—		T _J = 125°C, I _S = 35.5A, V _{GS} = 0V ③
t _{rr}	Reverse Recovery Time	—	38	57	ns	T _J = 25°C, I _F = 35.5A, V _R = 20V
Q _{rr}	Reverse Recovery Charge	—	45	68	nC	di/dt = 100A/μs ③
t _{rr}	Reverse Recovery Time	—	41	62	ns	T _J = 125°C, I _F = 35.5A, V _R = 20V
Q _{rr}	Reverse Recovery Charge	—	50	75	nC	di/dt = 100A/μs ③

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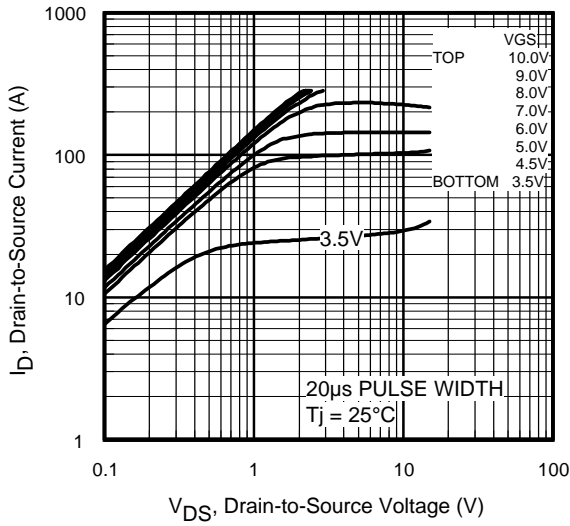


Fig 1. Typical Output Characteristics

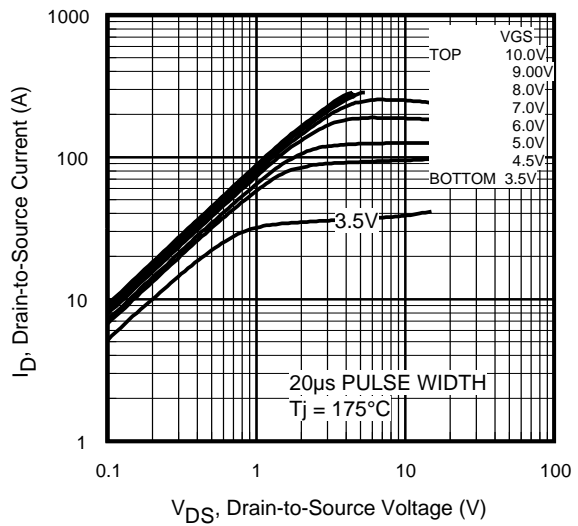


Fig 2. Typical Output Characteristics

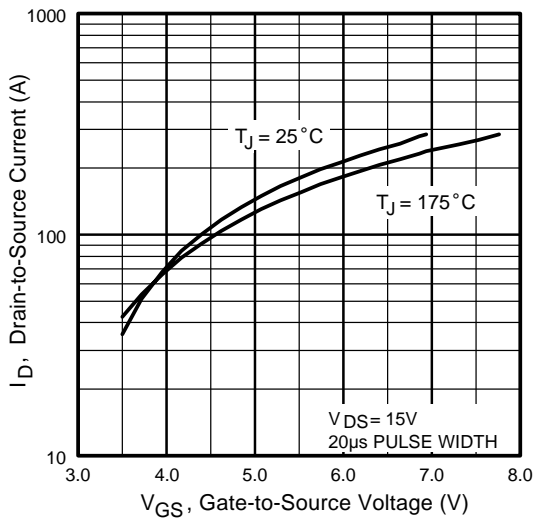


Fig 3. Typical Transfer Characteristics

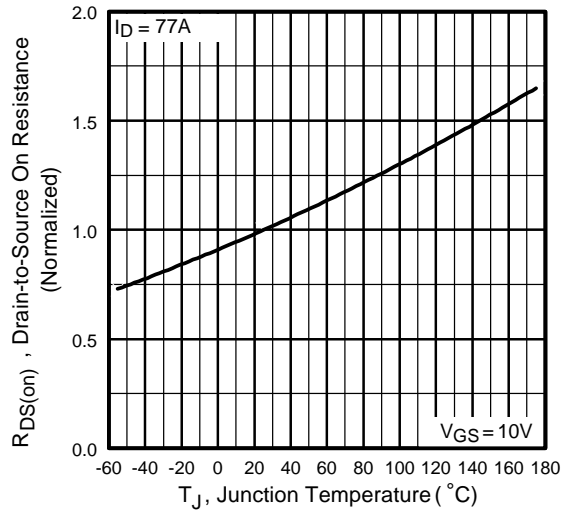


Fig 4. Normalized On-Resistance Vs. Temperature

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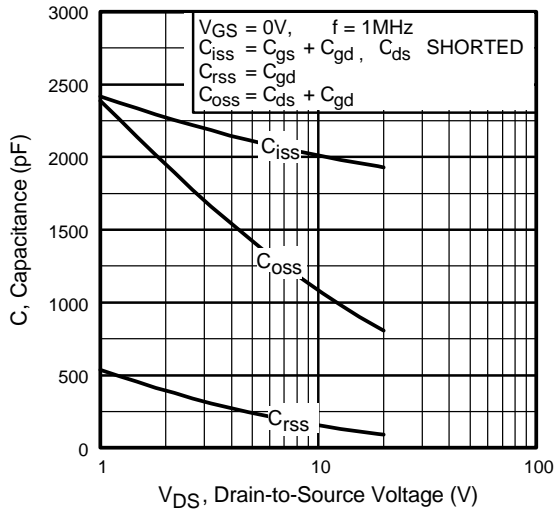


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

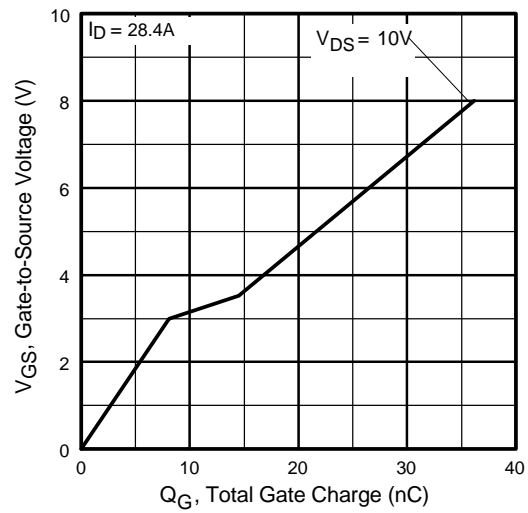


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

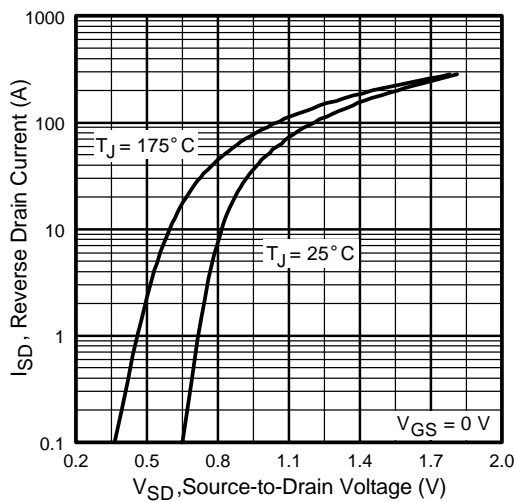


Fig 7. Typical Source-Drain Diode Forward Voltage

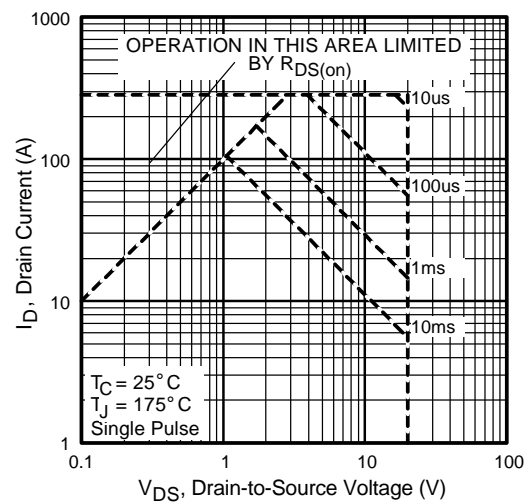


Fig 8. Maximum Safe Operating Area

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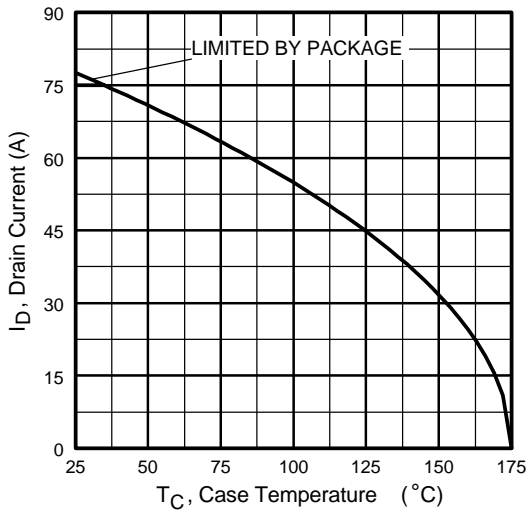


Fig 9. Maximum Drain Current Vs. Case Temperature

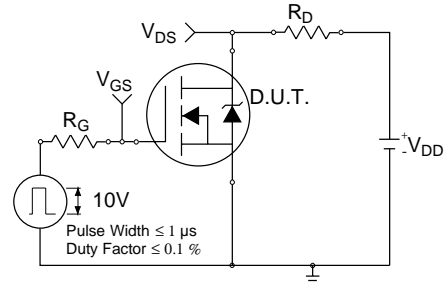


Fig 10a. Switching Time Test Circuit

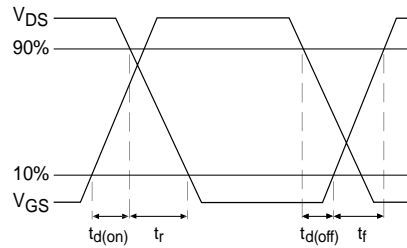


Fig 10b. Switching Time Waveforms

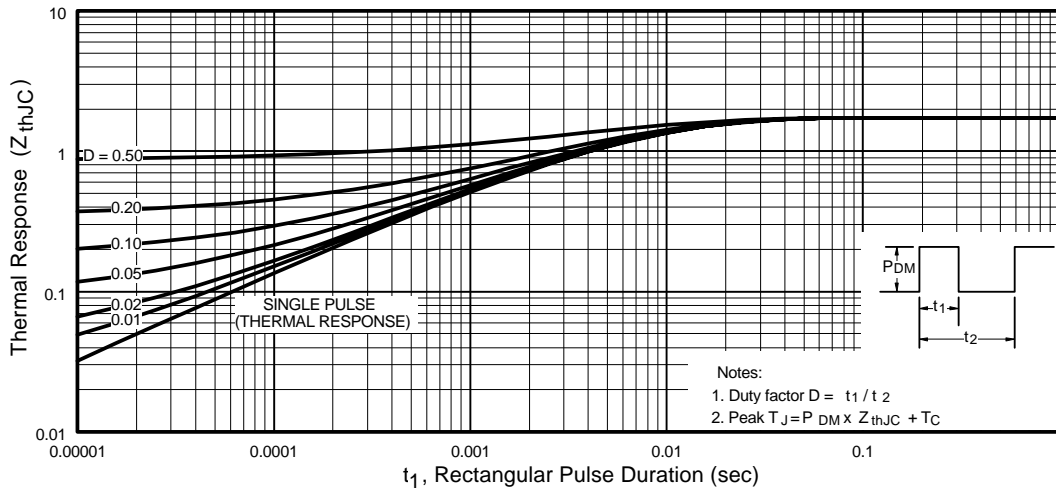


Fig 11. Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

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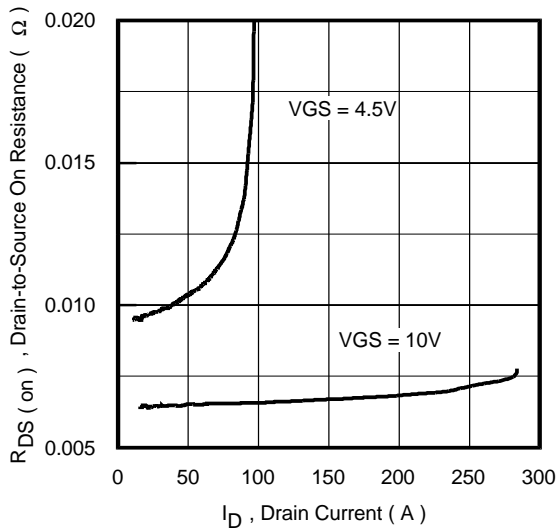


Fig 12. On-Resistance Vs. Drain Current

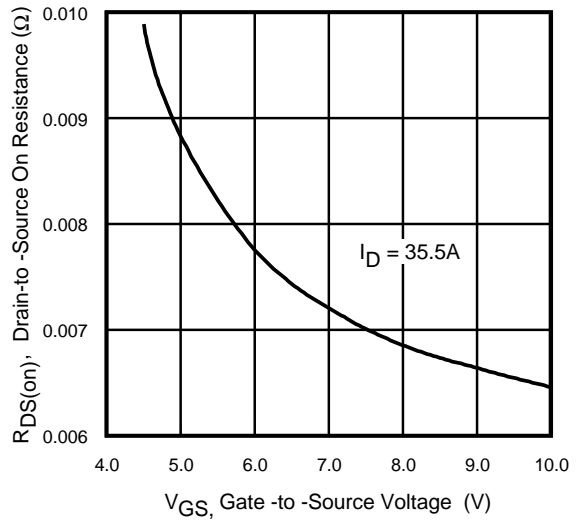


Fig 13. On-Resistance Vs. Gate Voltage

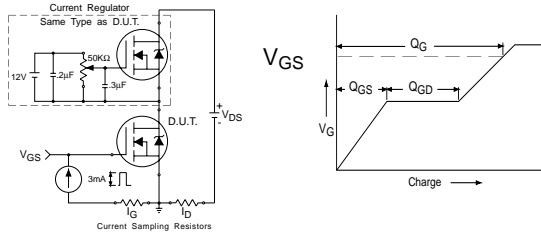


Fig 14a&b. Basic Gate Charge Test circuit and Waveforms

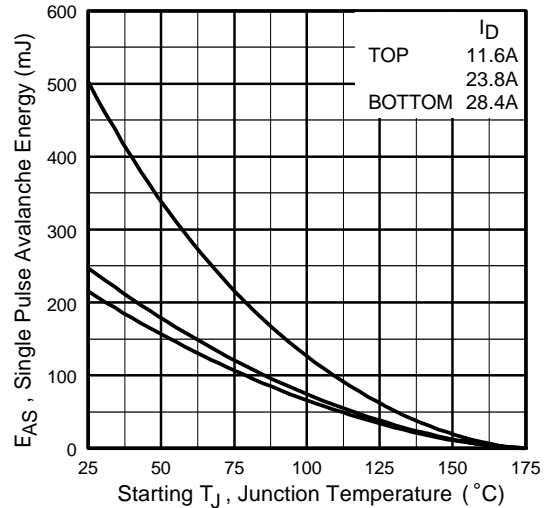


Fig 15c. Maximum Avalanche Energy Vs. Drain Current

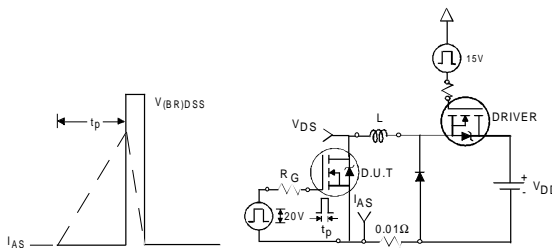


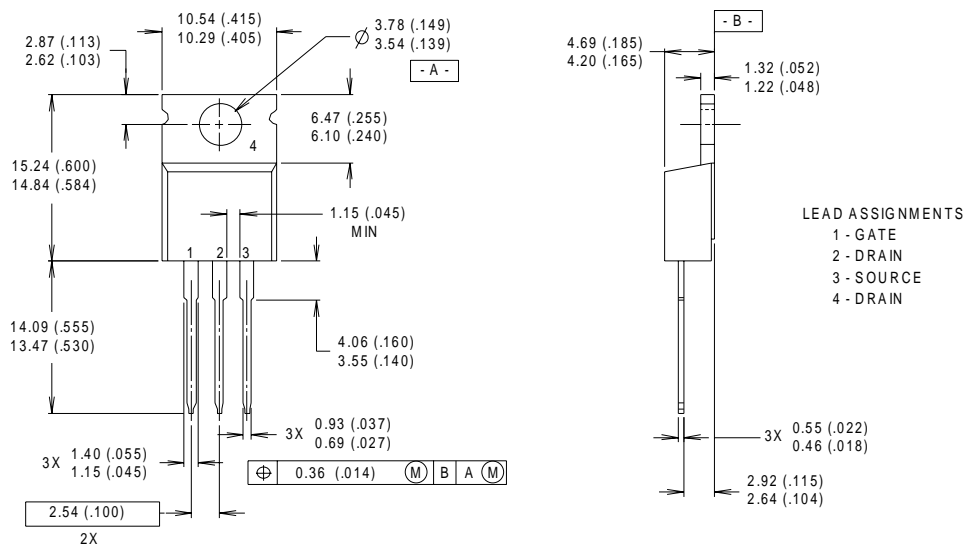
Fig 15a&b. Unclamped Inductive Test circuit and Waveforms

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TO-220AB Package Outline

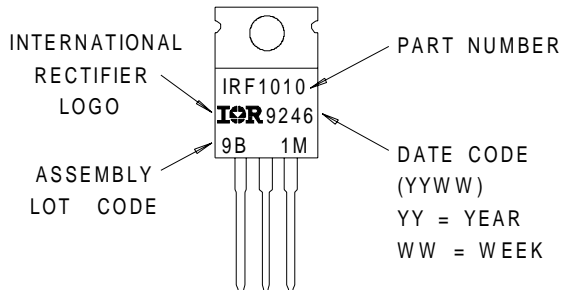
Dimensions are shown in millimeters (inches)



- NOTES:**
- 1 DIMENSIONING & TOLERANCING PER ANSI Y14.5M, 1982.
 - 2 CONTROLLING DIMENSION : INCH
 - 3 OUTLINE CONFORMS TO JEDEC OUTLINE TO-220AB.
 - 4 HEATSINK & LEAD MEASUREMENTS DO NOT INCLUDE BURRS.

TO-220AB Part Marking Information

EXAMPLE : THIS IS AN IRF1010
 WITH ASSEMBLY
 LOT CODE 9B1M

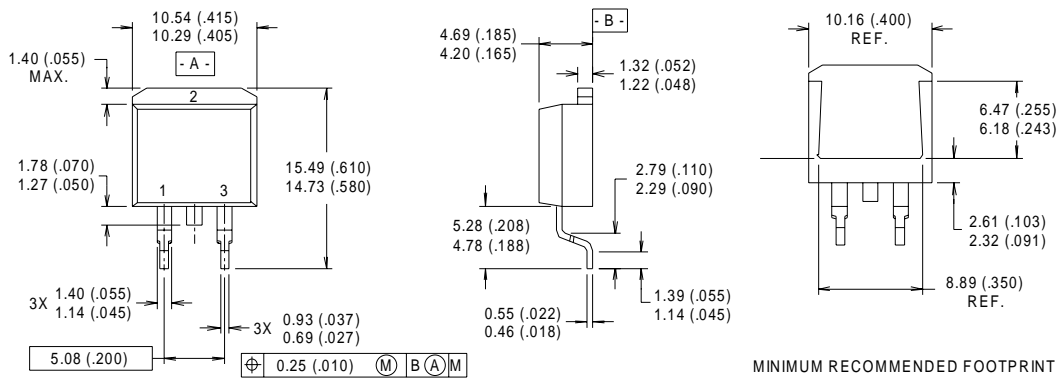


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D²Pak Package Outline

Dimensions are shown in millimeters (inches)



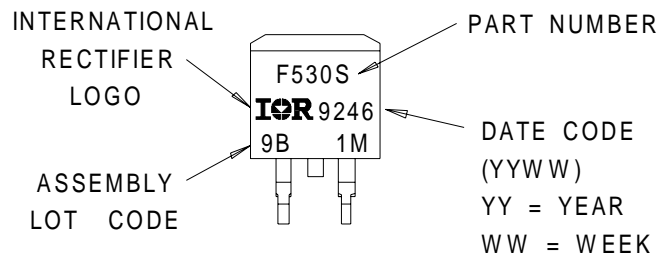
NOTES:

- 1 DIMENSIONS AFTER SOLDER DIP.
- 2 DIMENSIONING & TOLERANCING PER ANSI Y14.5M, 1982.
- 3 CONTROLLING DIMENSION : INCH.
- 4 HEATSINK & LEAD DIMENSIONS DO NOT INCLUDE BURRS.

LEAD ASSIGNMENTS

- 1 - GATE
- 2 - DRAIN
- 3 - SOURCE

D²Pak Part Marking Information

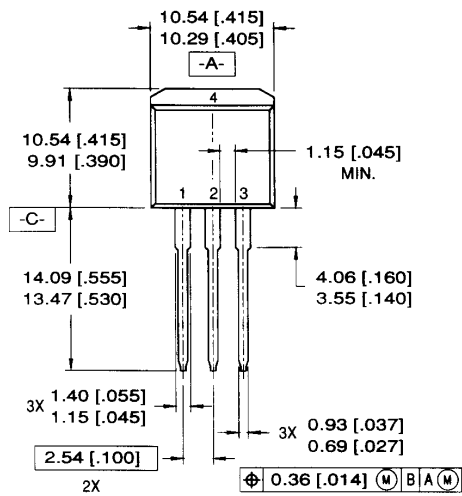


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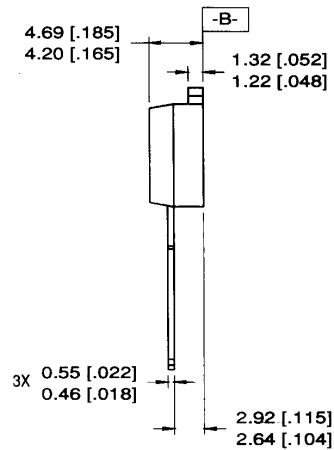
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TO-262 Package Outline

Dimensions are shown in millimeters (inches)



LEAD ASSIGNMENTS
 1 = GATE 3 = SOURCE
 2 = DRAIN 4 = DRAIN

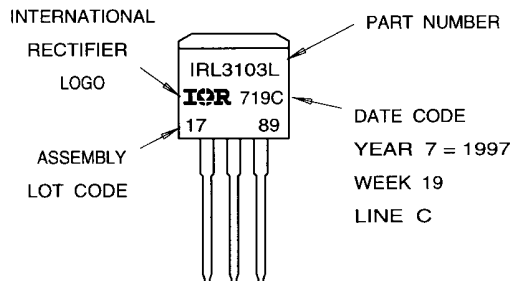


NOTES:

1. DIMENSIONING & TOLERANCING PER ANSI Y14.5M-1982
2. CONTROLLING DIMENSION: INCH.
3. DIMENSIONS ARE SHOWN IN MILLIMETERS (INCHES).
4. HEATSINK & LEAD DIMENSIONS DO NOT INCLUDE BURRS.

TO-262 Part Marking Information

EXAMPLE: THIS IS AN IRL3103L
 LOT CODE 1789
 ASSEMBLED ON WW 19, 1997
 IN THE ASSEMBLY LINE "C"

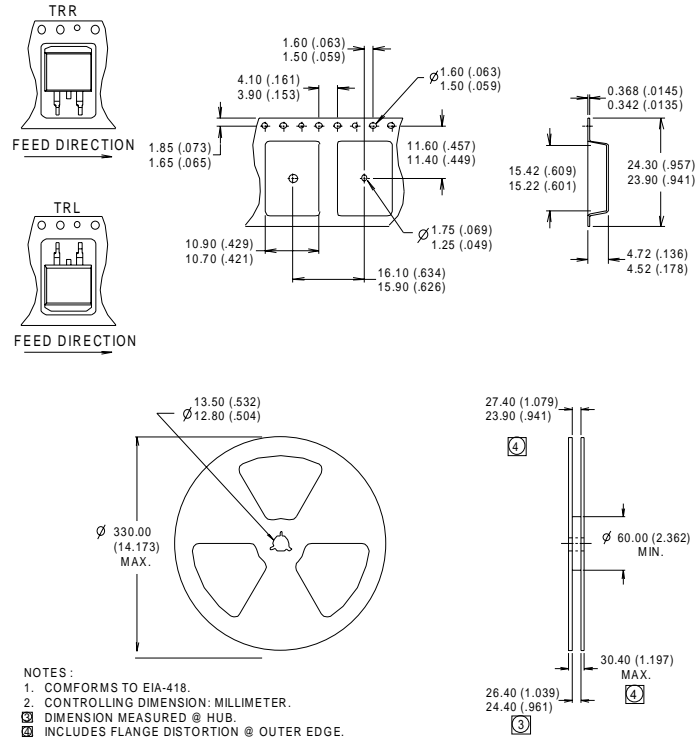


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D²Pak Tape & Reel Information

Dimensions are shown in millimeters (inches)



Notes:

- ① Repetitive rating; pulse width limited by max. junction temperature.
- ② Starting $T_J = 25^\circ\text{C}$, $L = 0.5 \text{ mH}$
 $R_G = 25\Omega$, $I_{AS} = 28.4 \text{ A}$.
- ③ Pulse width $\leq 300\mu\text{s}$; duty cycle $\leq 2\%$.
- ④ This is only applied to TO-220AB package
- ⑤ Calculated continuous current based on maximum allowable junction temperature. Package limitation current is 75A.

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IR TAIWAN: 16 Fl. Suite D. 207, Sec. 2, Tun Haw South Road, Taipei, 10673 Tel: 886-(0)2 2377 9936
Data and specifications subject to change without notice. 8/00

Note: For the most current drawings please refer to the IR website at:
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